## NSN 5961-01-297-2617

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-297-2617 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **Overall Diameter:** Between 0.667 inches and 0.687 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud Thready Qty Per Inch (tpi): 28 **Thread Size:** 0.250 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 13.0 regulator voltage, dc **Special Features:** Hardness critical item **Nuclear Hardness Critical Feature:** Hardened **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 wire loop and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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